NSN 5961-00-998-5684

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View Online at https://aerobasegroup.com/nsn/5961-00-998-5684 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Field effect **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 15.0 drain to source voltage and 30.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source and 30.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source **Current Rating Per Characteristic:** 20.00 milliamperes drain current and 10.00 amperes gate current **Power Rating Per Characteristic:** 300.0 milliwatts collector power dissipation **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 4 uninsulated wire lead **Specification Data:** 80131-release5238 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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